

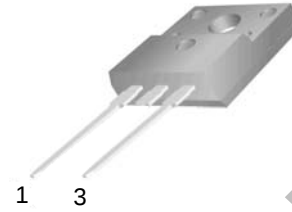


MURF2005-MURF2060

Features:

- ☐ High surge capacity
- ☐ Low Forward Voltage Drop.
- ☐ High Current Capability.
- ☐ Super Fast Switching Speed For High Efficiency

TO-220F -2L



Absolute Maximum Ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	MURF 2005	MURF 2010	MURF 2015	MURF 2020	MURF 2030	MURF 2040	MURF 2060	Unit
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	$V_{R(DC)}$	50	100	150	200	300	400	600	V
Average Rectified Forward Current Total Device, (Rated V_F),	$I_{F(AV)}$	20							A
Nonrepetitive Peak Surge Current(Surge applied at rated load conditions half wave, single phase, 60 Hz)	I_{FSM}	200							A
Operating Junction Temperature and Storage Temperature	T_J, T_{stg}	-55 to +155							°C
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.0				2.0			°C/W

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	MURF 2005	MURF 2010	MURF 2015	MURF 2020	MURF 2030	MURF 2040	MURF 2060	Unit
Forward Voltage ($I_F = 20A, T_C = 25^{\circ}C$) (Note 1) ($I_F = 20 A, T_C = 150^{\circ}C$)	V_F	0.975 0.895				1.30 1.00		1.50 1.20	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 150^{\circ}C$)	I_R	5 250				10 500			μA
Maximum Reverse Recovery Time ($I_F = 1.0 A, di/dt = 50 A/\mu s$) ($I_F = 0.5 A, I_R = 1.0 A, I_{REC} = 0.25 A$)	T_{RR}	35 25							ns

Note 1.Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

Typical Characteristics

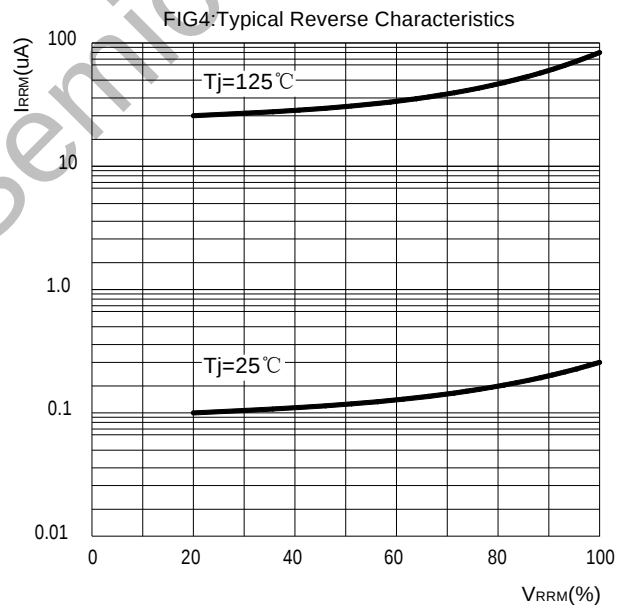
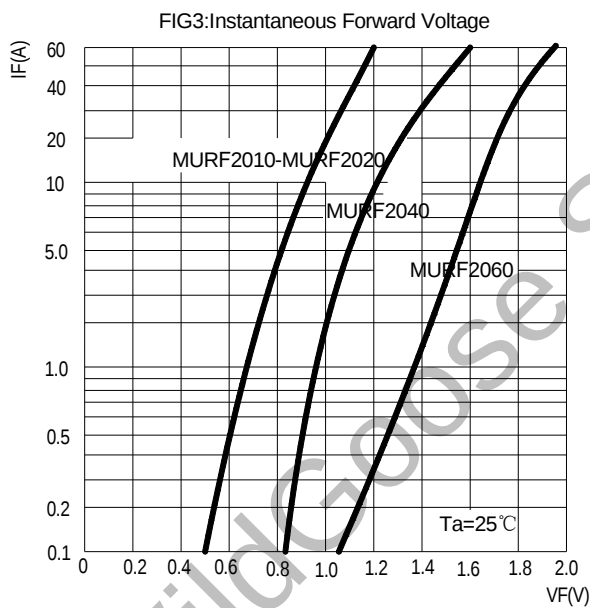
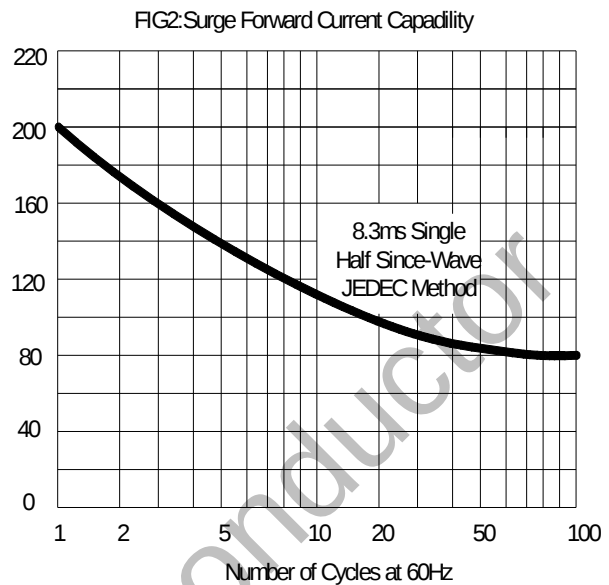
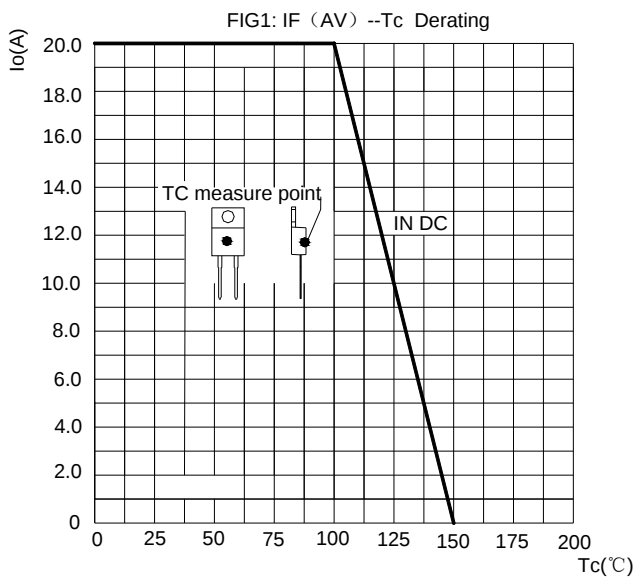
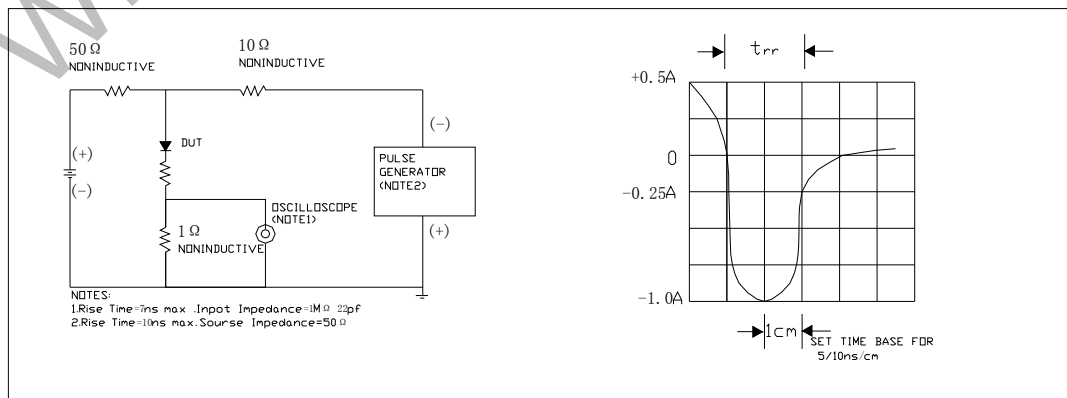
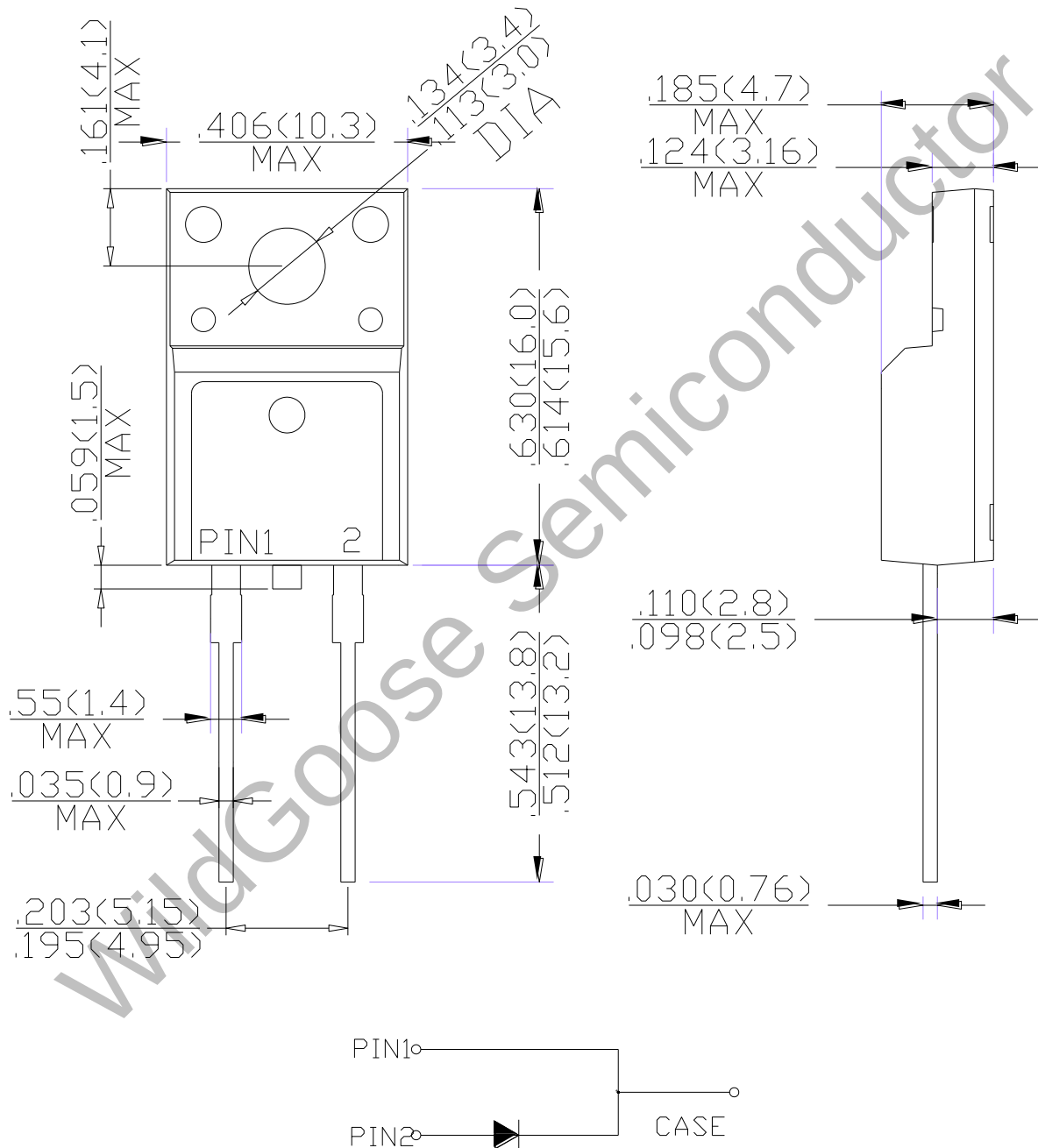


Diagram of circuit and Testing wave form of reverse recovery time



Package Dimension

TO-220F -2L



Dimensions in inches and (millimeters)